

RJF0613JSP

60 V - 10 A - N Channel MOS FET Power Switching R07DS0874EJ0100 Rev.1.00 Aug 29, 2012

Datasheet

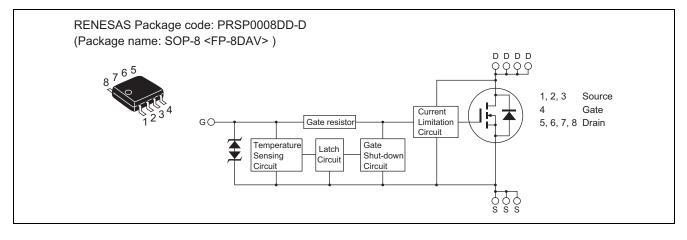
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation (4 V Gate drive).
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.
- High density mounting
- Power supply voltage applies 12 V and 24 V.
- AEC-Q101 Compliant

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	16	V
Gate to source voltage	V _{GSS}	-2.5	V
Drain current	ID Note3	10	А
Body-drain diode reverse drain current	I _{DR}	10	А
Avalanche current	I _{AP} Note 2	4.7	А
Avalanche energy	E _{AR} Note 2	94.7	mJ
Channel dissipation	Pch Note 1	2.5	W
Channel temperature	Tch	150	٥°
Storage temperature	Tstg	-55 to +150	۵°

Notes: 1. When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW \leq 10s

2. Tch = 25°C, Rg \geq 50 Ω

3. It provides by the current limitation lower bound value.



Typical Operation Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	3.5	—	—	V	
	VIL	—	—	1.2	V	
Input current	I _{IH1}	_		100	μA	Vi = 8 V, V _{DS} = 0
(Gate non shut down)	I _{IH2}	_		50	μA	Vi = 3.5 V, V _{DS} = 0
	IIL	_		1	μA	Vi = 1.2 V, V _{DS} = 0
Input current	I _{IH(sd)1}	_	0.8	_	mA	Vi = 8 V, V _{DS} = 0
(Gate shut down)	I _{IH(sd)2}	_	0.35	_	mA	Vi = 3.5 V, V _{DS} = 0
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
Gate operation voltage	Vop	3.5	—	12	V	
Drain current (Current limitation value)	I _{D limt}	10	_	—	A	V_{GS} = 5 V, V_{DS} = 10 V ^{Note 4}

Note: 4. Pulse test

Electrical Characteristics

						$(Ta = 25^{\circ}C)$
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	_	—	45	А	V_{GS} = 3.5 V, V_{DS} = 10 V ^{Note 5}
	I _{D2}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} = 10 V
	I _{D3}	10	—	_	А	V_{GS} = 5 V, V_{DS} = 10 V ^{Note 5}
Drain to source breakdown voltage	V _{(BR)DSS}	60	_	—	V	$I_{\rm D}$ = 10 mA, $V_{\rm GS}$ = 0
Gate to source breakdown	V _{(BR)GSS}	16	_	_	V	$I_{\rm G}$ = 800 μ A, $V_{\rm DS}$ = 0
voltage	V _{(BR)GSS}	-2.5	_	_	V	$I_{\rm G} = -100 \ \mu \text{A}, \ V_{\rm DS} = 0$
Gate to source leak current	I _{GSS1}	_	_	100	μA	$V_{GS} = 8 V, V_{DS} = 0$
	I _{GSS2}	_	_	50	μA	V_{GS} = 3.5 V, V_{DS} = 0
	I _{GSS3}	_	—	1	μΑ	V_{GS} = 1.2 V, V_{DS} = 0
	I _{GSS4}	_	—	-100	μA	$V_{GS} = -2.4 V, V_{DS} = 0$
Input current (shut down)	I _{GS(OP)1}	_	0.8	_	mA	$V_{GS} = 8 V, V_{DS} = 0$
	I _{GS(OP)2}	_	0.35	_	mA	V_{GS} = 3.5 V, V_{DS} = 0
Zero gate voltage drain current	I _{DSS}	_	—	10	μΑ	V _{DS} = 32 V, V _{GS} = 0, Ta = 125°C
Gate to source cutoff voltage	V _{GS(off)}	1.1	_	2.1	V	V _{DS} = 10 V, I _D = 1 mA
Forward transfer admittance	y _{fs}	12	17	—	S	$I_D = 5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 5}}$
Static drain to source on state	R _{DS(on)}	_	30	40	mΩ	$I_D = 5 \text{ A}, V_{GS} = 4 \text{ V}^{\text{Note 5}}$
resistance	R _{DS(on)}	_	21	30	mΩ	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 5}}$
Output capacitance	Coss	_	520	—	pF	V_{DS} = 10 V, V_{GS} = 0, f = 1MHz
Turn-on delay time	t _{d(on)}	_	3.5	—	μS	V_{GS} = 10 V, I_D = 5 A, R_L = 2 Ω
Rise time	tr		11	—	μS	
Turn-off delay time	t _{d(off)}		7	—	μS	
Fall time	t _f	_	12	—	μS	
Body-drain diode forward voltage	V _{DF}	_	0.9	—	V	I _F = 10 A, V _{GS} = 0
Body-drain diode reverse recovery time	t _{rr}		63		ns	$I_F = 10 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu \text{s}$
Over load shut down	t _{os1}		0.4		ms	V _{GS} = 5 V, V _{DD} = 16 V
operation time Note 6	t _{os2}		0.25		ms	V _{GS} = 5 V, V _{DD} = 24 V

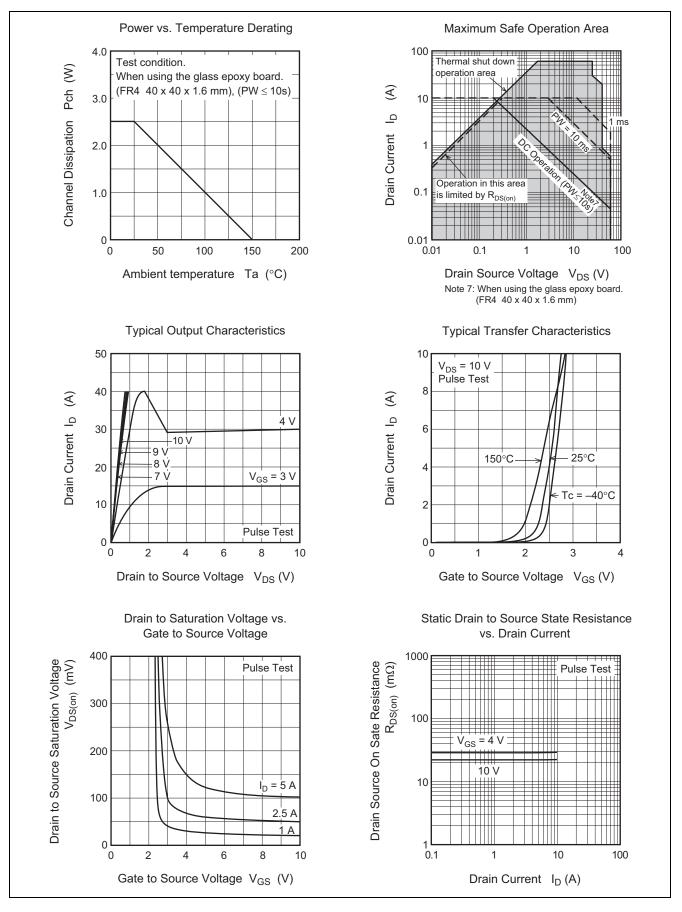
Notes: 5. Pulse test

6. Including the junction temperature rise of the over loaded condition.

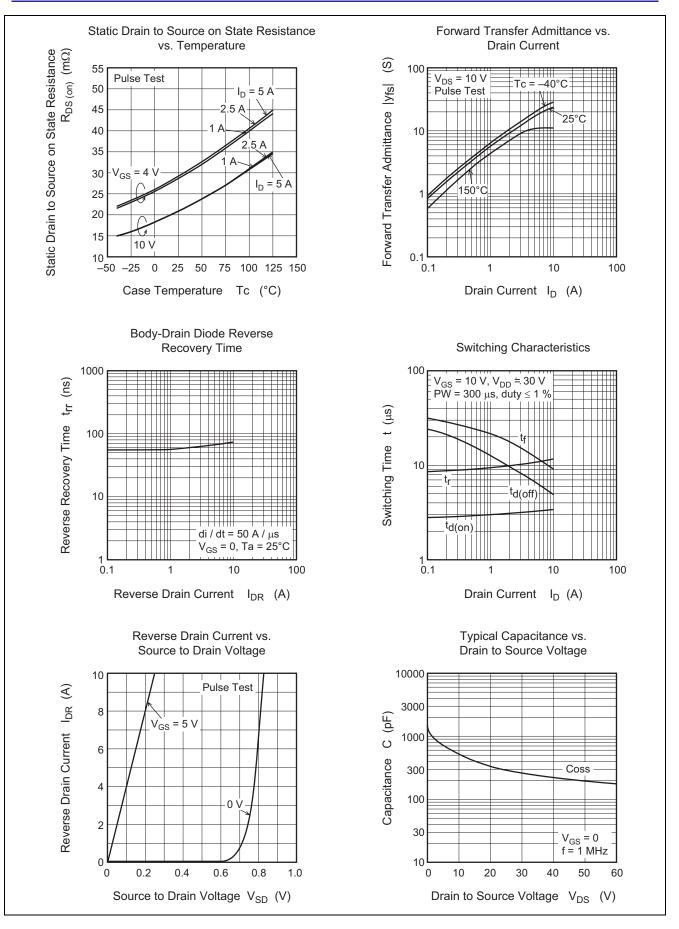
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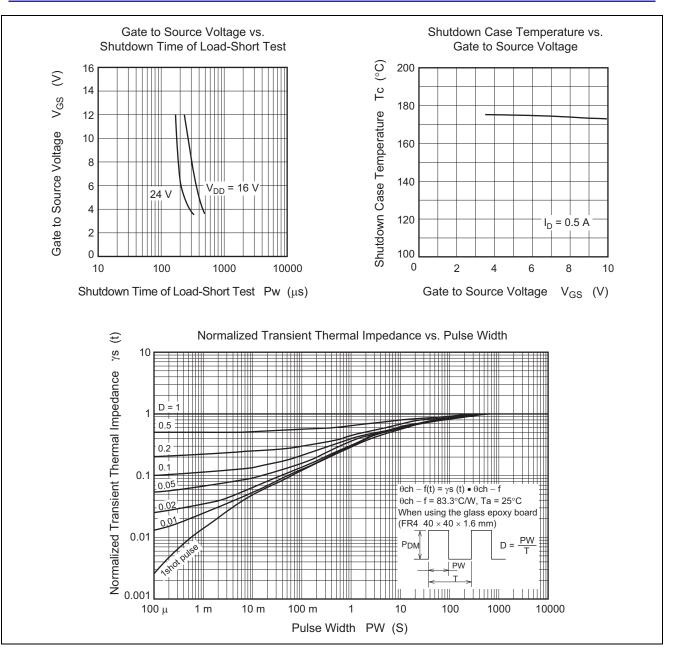
Main Characteristics



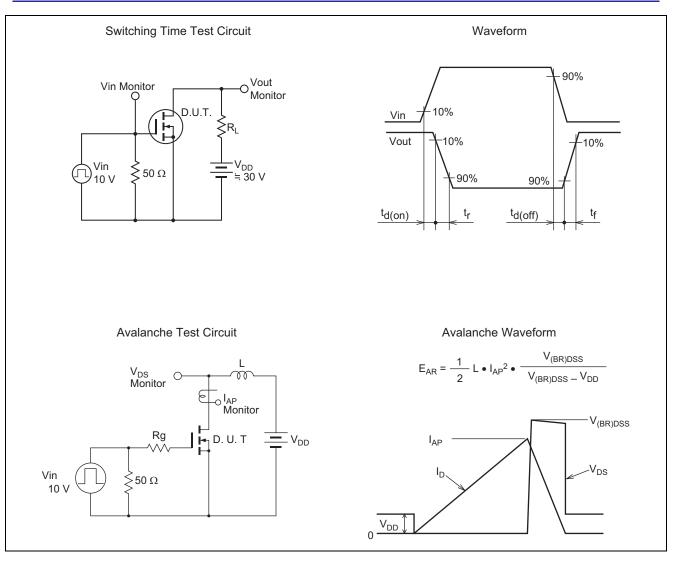






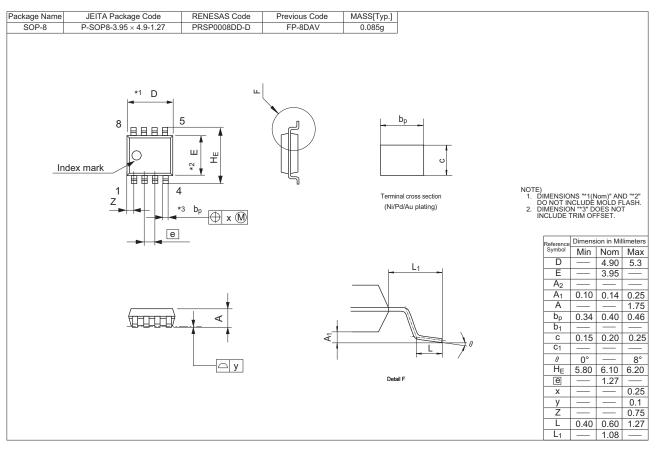








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container		
RJF0613JSP-00-J0	2500 pcs	Taping		

Note: The symbol of 2nd "-" is occasionally presented as "#".



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